

**ELECTRICAL SPECIFICATIONS**  
(25°C UNLESS OTHERWISE SPECIFIED)

**INPUT (CONTROL) SPECIFICATIONS**

Parameter	Min	Max	Units
Control Voltage Range (See Figures 1, 2 and Note 1)	3.8	32	Vdc
Input Current @ 5 V (See Figures 1 and 2)		12	mAdc
Must Turn-On Voltage	3.8		Vdc
Must Turn-Off Voltage (Guaranteed Off)		1.5	Vdc
Reverse Voltage Protection		-32	Vdc

**OUTPUT (LOAD) SPECIFICATIONS**

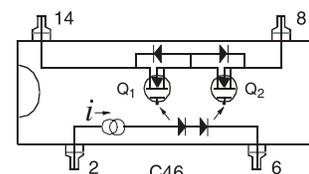
Parameter	DC		Bi-directional		Units
	Min	Max	Min	Max	
Output Voltage Rating	C47F-10	50	C46F-10	±50	Vdc
	C47F-20	90	C46F-20	±90	Vdc
	C47F-30	180	C46F-30	±180	Vdc
	C47F-40	360	C46F-40	±360	Vdc
Output Current Rating (See Figure 3)	C47F-10	1.75	C46F-10	1.0	Adc
	C47F-20	1.0	C46F-20	0.75	Adc
	C47F-30	0.6	C46F-30	0.4	Adc
	C47F-40	0.4	C46F-40	0.25	Adc
On Resistance (See Note 3)	C47F-10	0.15	C46F-10	0.3	Ohms
	C47F-20	0.35	C46F-20	0.7	Ohms
	C47F-30	1.0	C46F-30	2.0	Ohms
	C47F-40	2.0	C46F-40	4.0	Ohms
Leakage Current at Rated Voltage		1.0		1.0	mAdc
Surge Rating (% of Rated) <1 sec		200		200	%
Turn-On Time	C47F-10	3	C46F-10,30,40	3	ms
	C47F-20,30,40	1.5	C46F-10	5	ms
Turn-Off Time		1.0		1.0	ms
	C47F-10	700	C46F-10	700	pf
Output Capacitance (Typical)	C47F-20	350	C46F-20	350	pf
	C47F-30	300	C46F-30	300	pf
	C47F-40	250	C46F-40	250	pf
Insulation Resistance		10 <sup>9</sup>		10 <sup>9</sup>	Ohms
Dielectric Strength (Input to Output)		1500		1500	Vac
Capacitance (Input to Output)		10		10	pF

**FEATURES/BENEFITS**

- Power FET Output with Very Low On Resistance: Virtually no offset with low leakage and voltage drop.
- Switches High Voltages and Currents: Voltages to 360 Vdc. Current to 1.75 Adc. DC, Bi-directional or AC models
- Optical Isolation: Isolates control elements from load transients. Eliminates ground loops and signal ground noise.
- Floating Output: Allows for high and low side switching.
- High Noise Immunity: Control circuit can not be triggered by output switching noise.
- 14-pin DIP package

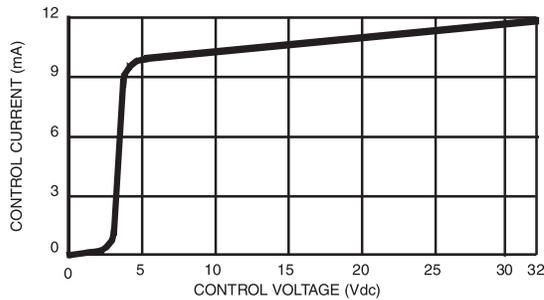
**DESCRIPTION**

These miniature solid-state relays utilize a photovoltaic generator driving high performance power FET chips to provide low output on-resistance and high output switching capability. The series includes DC switching versions with output current ratings up to 1.75 amp, and bi-directional versions to switch AC or DC up to 1.0 amp. Output voltage ratings of both types range from 50 to 360 volts. The virtual elimination of offset voltage makes them ideal for low level switching applications as well. Input and output are optically isolated to protect input logic circuits from output voltage transients.

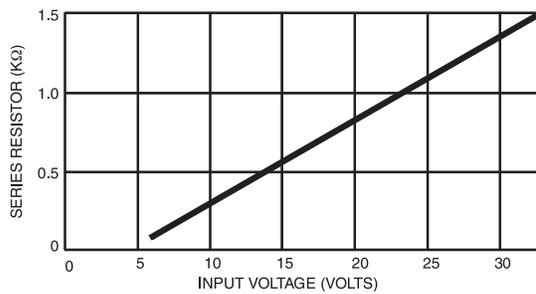


C47 is the same configuration except Q<sub>2</sub> has been replaced with a wire short

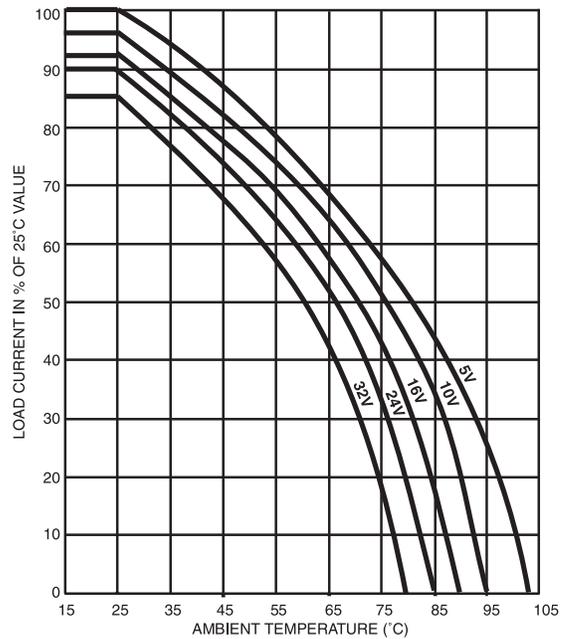
**CHARACTERISTIC CURVES**



**CONTROL CURRENT VS CONTROL VOLTAGE**  
FIGURE 1

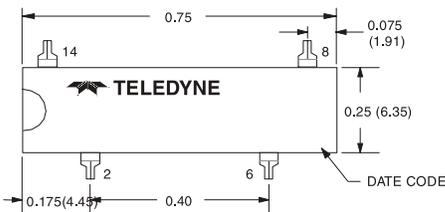
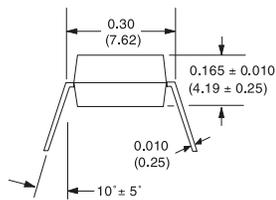
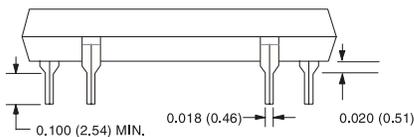


**SERIES LIMIT RESISTOR VS INPUT VOLTAGE**  
FIGURE 2



**MAXIMUM LOAD CURRENT VS TEMPERATURE**  
FIGURE 3

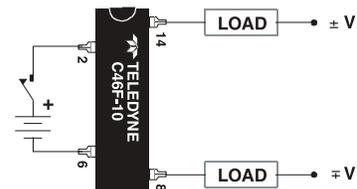
**MECHANICAL SPECIFICATION**



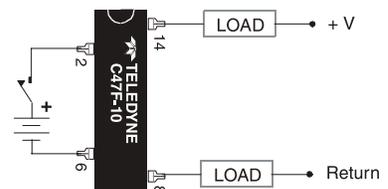
**DIMENSIONS ARE SHOWN IN INCHES (MILLIMETERS)**  
Tolerances ± 0.015 (0.38) unless otherwise specified

- Operating Temperature -40°C to 100°C.
- Storage Temperature -40°C to 100°C.
- Weight: 2.0 grams maximum
- Case: 14 pin Dual-In-Line (TO-116)
- Case Material: Epoxy, self extinguishing

**TYPICAL INTERFACE**



**BI-DIRECTIONAL OR AC MODEL**



**DC MODELS**

Loads may be connected in either output terminal

**NOTES:**

1. For control voltages above 6 volts a series resistor is required. Use standard value selected from Figure 2.
2. Surge current duty cycle 10% maximum. Surge duration not to exceed 1 second.
3. To calculate output On-Resistance for junction temperatures other than 25°C use the following equation:

$$R_T = R_{25} e^{0.006 \times \Delta T} \text{ where } R_{25} = \text{Resistance at } 25^\circ\text{C}$$

$R_T = \text{Resistance at elevated temperature}$   
 $\Delta T = \text{Elevated temperature} - 25^\circ\text{C}$